

## Features

- Trench LV MOSFET Technology
- Moisture Sensitivity Level 1
- Halogen Free. "Green" Device (Note1)
- Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

## Maximum Ratings

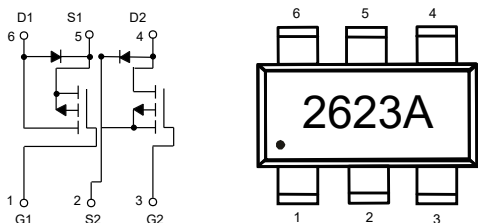
- Operating Junction Temperature Range : -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C
- Thermal Resistance: 100°C/W Junction to Ambient(Note2)

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	$V_{DS}$	-30	V
Gate-Source Voltage	$V_{GS}$	±20	V
Continuous Drain Current	$I_D$	$T_A=25^\circ\text{C}$	-3
		$T_A=100^\circ\text{C}$	-1.9
Pulsed Drain Current (Note3)	$I_{DM}$	-12	A
Total Power Dissipation (Note4)	$P_D$	1.25	W

Note:

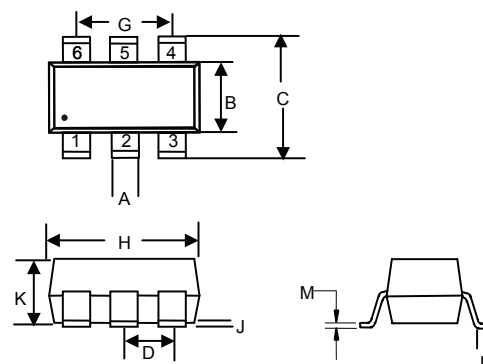
1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
2. The value of  $R_{\theta JA}$  is measured with the device mounted on 1in<sup>2</sup> FR-4 board with 2oz. Copper, in a still air environment with  $T_A=25^\circ\text{C}$ .
3. Repetitive rating; pulse width limited by max. junction temperature.
4.  $P_D$  is based on max. junction temperature, using junction-ambient thermal resistance.

## Internal Structure and Marking Code



# Dual P-Channel MOSFET

## SOT23-6L



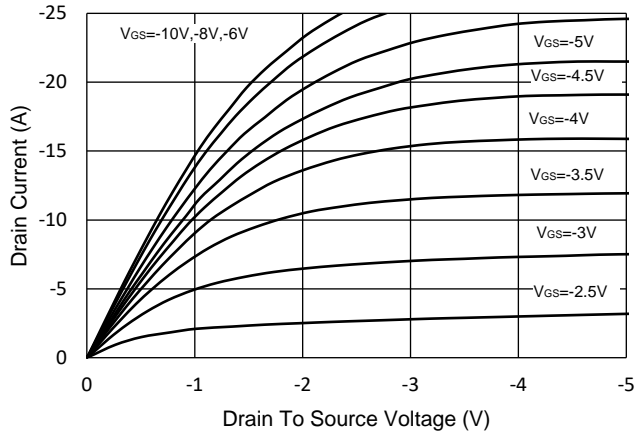
DIM	DIMENSIONS				NOTE
	INCHES		MM		
	MIN	MAX	MIN	MAX	
A	0.012	0.020	0.30	0.50	
B	0.051	0.070	1.30	1.80	
C	0.087	0.126	2.20	3.20	
D	0.037		0.95		TYP.
G	0.074		1.90		TYP.
H	0.106	0.122	2.70	3.10	
J	0.002	0.006	0.05	0.15	
K	0.030	0.051	0.75	1.30	
L	0.012	0.024	0.30	0.60	
M	0.003	0.008	0.08	0.22	

**Electrical Characteristics @ 25°C (Unless Otherwise Specified)**

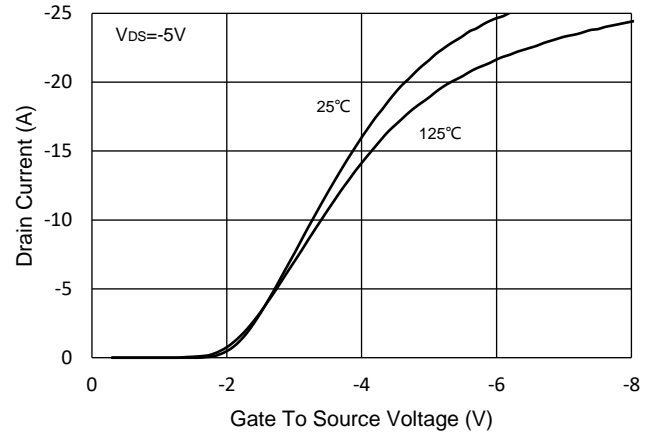
Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
<b>Static Characteristics</b>						
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS}=0V, I_D=-250\mu A$	-30			V
Gate-Source Leakage Current	$I_{GSS}$	$V_{DS}=0V, V_{GS}=\pm 20V$			$\pm 100$	nA
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS}=-30V, V_{GS}=0V$			-1	$\mu A$
Gate-Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=-250\mu A$	-1.0	-1.5	-2.5	V
Drain-Source On-Resistance	$R_{DS(on)}$	$V_{GS}=-10V, I_D=-3A$		65	90	m $\Omega$
		$V_{GS}=-4.5V, I_D=-2A$		88	115	
Forward Transconductance	$g_{FS}$	$V_{DS}=-5V, I_D=-3A$		7		S
Gate Resistance	$R_g$	f=1 MHz, Open drain		9		$\Omega$
<b>Diode Characteristics</b>						
Continuous Body Diode Current	$I_S$				-3	A
Diode Forward Voltage	$V_{SD}$	$V_{GS}=0V, I_S=-1A$			-1.2	V
Reverse Recovery Time	$t_{rr}$	$I_F=-3A, di/dt=100A/\mu s$		12		ns
Reverse Recovery Charge	$Q_{rr}$			4.4		nC
<b>Dynamic Characteristics</b>						
Input Capacitance	$C_{iss}$	$V_{DS}=-15V, V_{GS}=0V, f=1MHz$		356		pF
Output Capacitance	$C_{oss}$			44		
Reverse Transfer Capacitance	$C_{riss}$			36		
Total Gate Charge	$Q_g$	$V_{DS}=-15V, V_{GS}=-10V, I_D=-3A$		7.6		nC
Gate-Source Charge	$Q_{gs}$			1.2		
Gate-Drain Charge	$Q_{gd}$			1		
Turn-On Delay Time	$t_{d(on)}$	$V_{DD}=-15V, V_{GS}=-10V, R_G=2.5\Omega, I_D=-1A$		6		ns
Turn-On Rise Time	$t_r$			3.4		
Turn-Off Delay Time	$t_{d(off)}$			16		
Turn-Off Fall Time	$t_f$			4.3		

**Curve Characteristics**

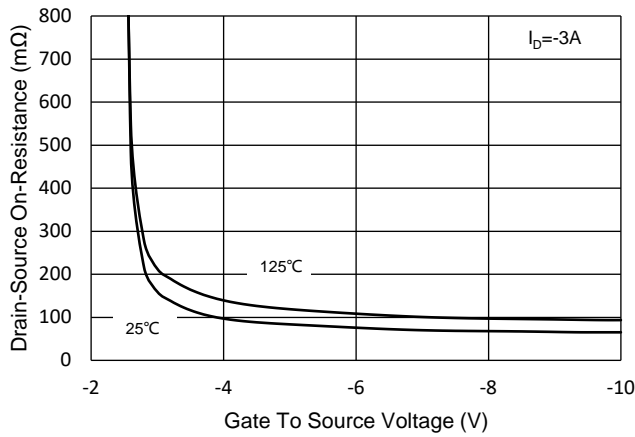
**Fig.1 - Typical Output Characteristics**



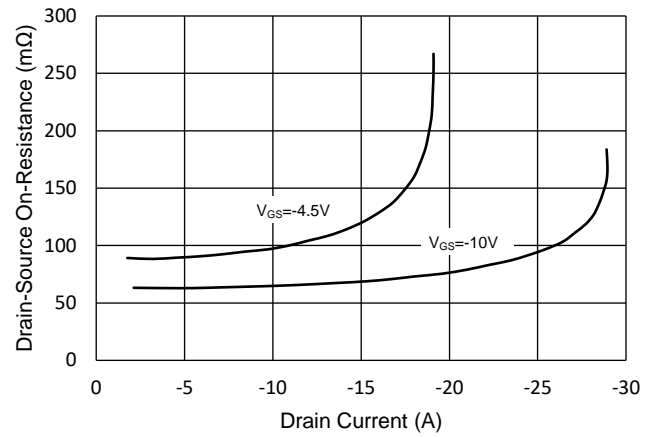
**Fig.2 - Transfer Characteristic**



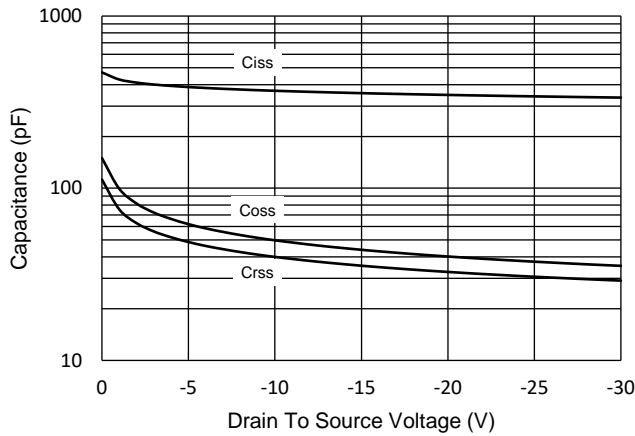
**Fig.3 -  $R_{DS(ON)}$  -  $V_{GS}$**



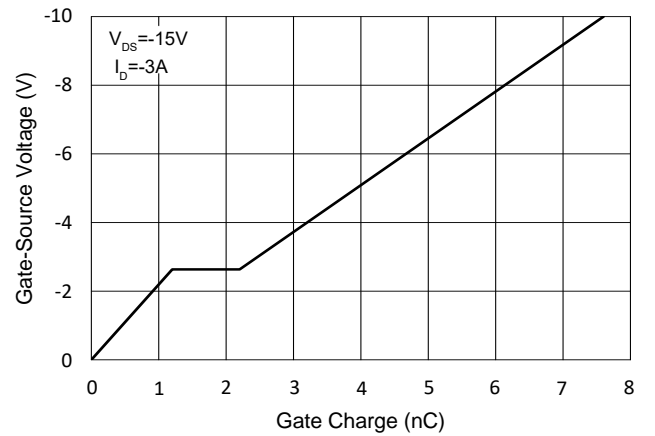
**Fig.4 -  $R_{DS(ON)}$  -  $I_D$**



**Fig.5 - Capacitance Characteristics**

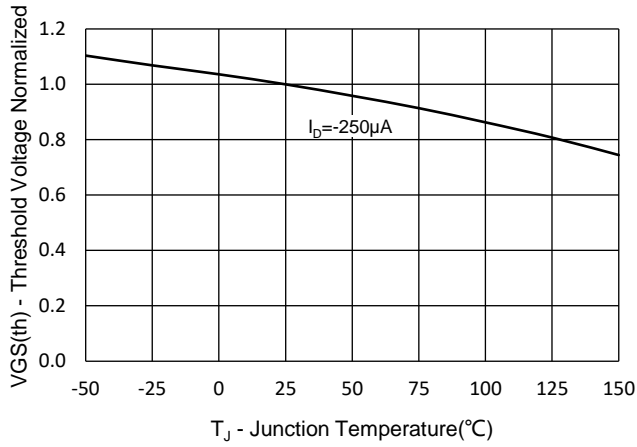


**Fig.6 - Gate Charge**

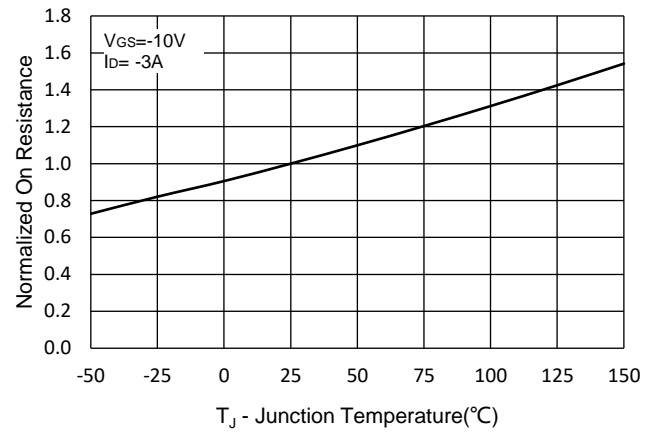


## Curve Characteristics

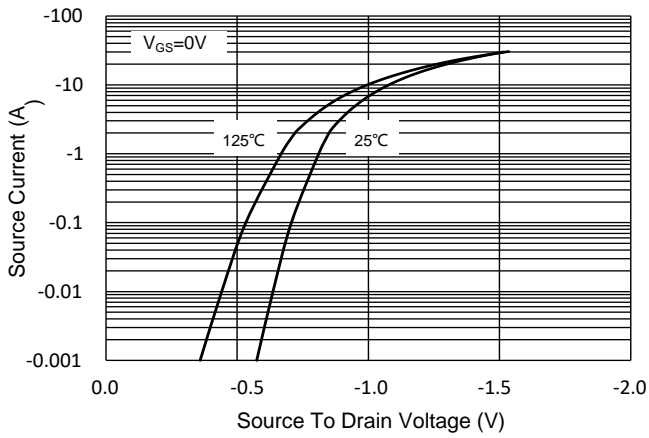
**Fig.7 - Normalized Threshold Voltage**



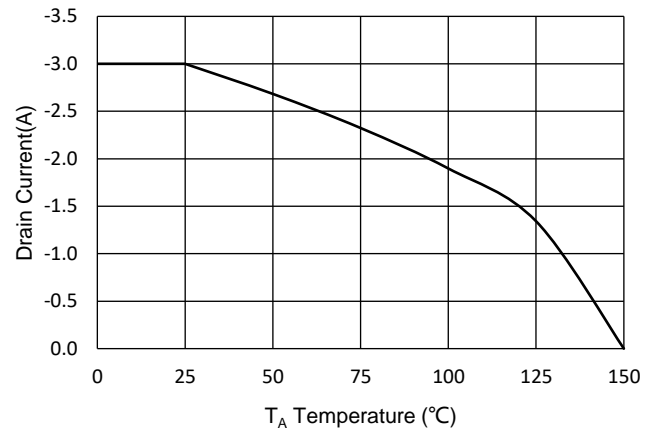
**Fig.8 - Normalized On Resistance Characteristics**



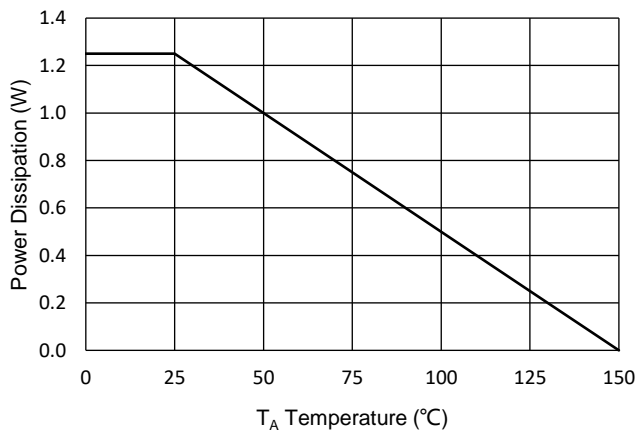
**Fig.9 - I<sub>S</sub> - V<sub>SD</sub>**



**Fig.10 - Drain Current**

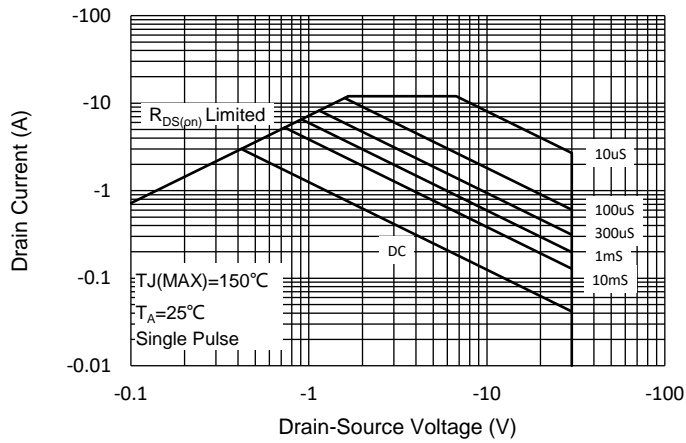


**Fig.11 - PD Dissipation**

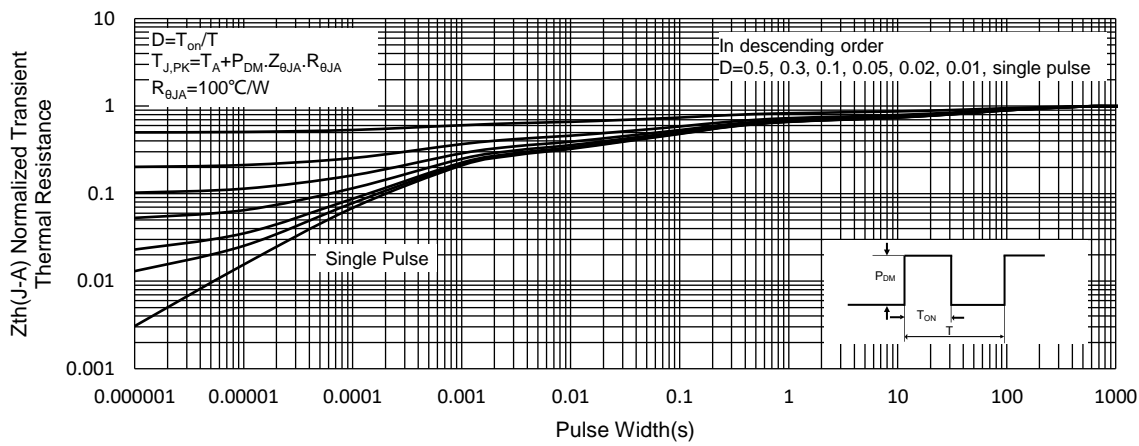


## Curve Characteristics

**Fig.12 - Safe Operation Area**



**Fig.13 - Normalized Transient Thermal Impedance**



## Ordering Information

Device	Packing
Part Number-TP	Tape&Reel: 3Kpcs/Reel

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